


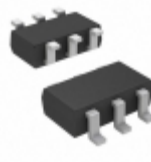
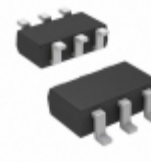


	<p><b>SI3586DV-T1-GE3</b></p>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI3586DV-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N/P-CH 20V 2.9A 6-TSOP</p> <p><b>Datenblätter:</b>  <a href="#">SI3586DV-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 125897 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3586DV-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N/P-CH 20V 2.9A 6-TSOP
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	125897 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	830mW
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Typ FET	N and P-Channel
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.9A, 2.1A
Rds On (Max) @ Id, Vgs	60 mOhm @ 3.4A, 4.5V
VGS (th) (Max) @ Id	1.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)










































SI3586DV-T1-GE3 ist neu im Original, Suche SI3586DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3586DV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3586DV-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI3586DV</b> VISHAY SI3586DV VISHAY</p>	 <p><b>SI3588DV-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.5A 6TSOP</p>	 <p><b>SI3586DV-T1-E3</b> Vishay / Siliconix MOSFET N/P-CH 20V 2.9A 6TSOP</p>	 <p><b>SI3588DV-T1-E3</b> Vishay / Siliconix MOSFET N/P-CH 20V 2.5A 6TSOP</p>
 <p><b>SI3586DV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.9A 6- TSOP</p>	 <p><b>SI3588DV-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.5A 6- TSOP</p>	 <p><b>SI3586DV-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V 2.9A 6TSOP</p>	 <p><b>SI3588DV</b> VISHAY SI3588DV VISHAY</p>

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|---------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------|
|  SI3499DV-T1-GE3 |  SI3499DV-T1-GE3  |  SI3500-A-GM      |  SI3529DV-T1-GE3  |  SI3529DV-T1-GE3 |
|  SI3552DV        |  SI3552DV-T1      |  SI3552DV-T1-E3   |  SI3552DV-T1-E3   |  SI3552DV-T1-GE3 |
|  SI3552DV-T1-GE3 |  SI3585CDV        |  SI3585CDV-T1-GE3 |  SI3585CDV-T1-GE3 |  SI3585DV        |
|  SI3585DV-T1     |  SI3585DV-T1-E3   |  SI3585DV-T1-E3   |  SI3585DV-T1-GE3  |  SI3585DV-T1-GE3 |
|  SI3586DS-TI-E3  |  SI3586DV         |  SI3586DV-T1-E3   |  SI3586DV-T1-E3   |  SI3586DV-T1-GE3 |
|  SI3588DV        |  SI3588DV-T1-E3   |  SI3588DV-T1-E3   |  SI3588DV-T1-GE3  |  SI3588DV-T1-GE3 |
|  SI3590DV-T1-GE3 |  SI3590DV-T1-GE3  |  SI3801DV-T1      |  SI3803DV-T1      |  SI3805DV-T1     |
|  SI3805DV-T1-E3  |  SI3805DV-T1-E3   |  SI3812DV-T1-GE3  |  SI3812DV-T1-GE3  |  SI3850ADV-T1-E3 |
|  SI3850ADV-T1-E3 |  SI3850ADV-T1-GE3 |  SI3850ADV-T1-GE3 |  SI3850DV-T1      |  SI3850DV-T1-E3  |
|  SI3850DV-T1-GE3 |  SI3851DV         |  SI3851DV-T1      |  SI3851DV-T1-E3   |  SI3851DV-T1-E3  |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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